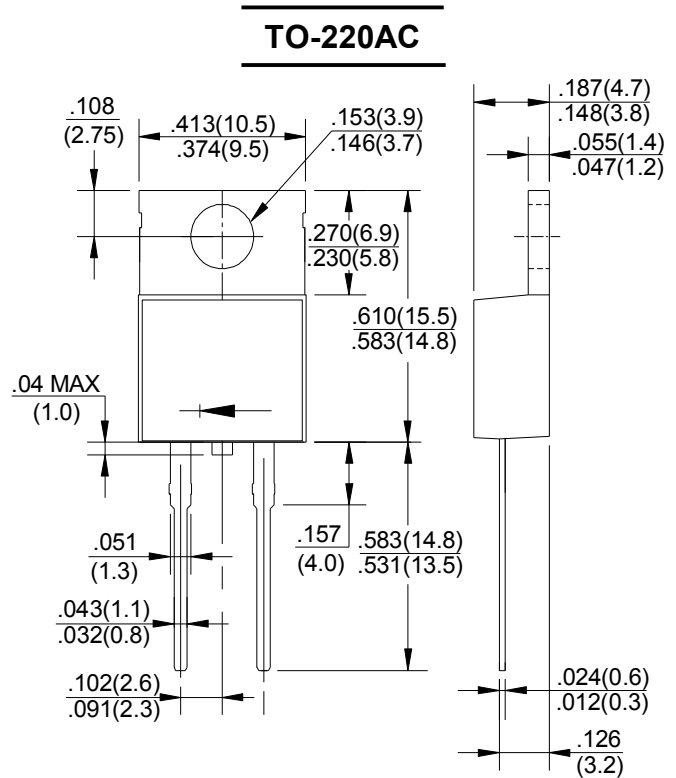


FEATURES

- Metal of silicon rectifier , majority carrier conduction
- Guard ring for transient protection
- Low power loss,high efficiency
- High current capability,low VF
- High surge capacity
- Plastic package has UL flammability classification 94V-0
- For use in low voltage,high frequency inverters,free wheeling,and polarity protection applications

MECHANICAL DATA

- Case: TO-220AC molded plastic
- Polarity: As marked on the body
- Weight: 0.08ounces,2.24 grams
- Mounting position :Any



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave ,60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	MBR1030	MBR1040	MBR1050	MBR1060	MBR1080	MBR10100	UNIT
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	30	40	50	60	80	100	V
Maximum RMS Voltage	V _{RMS}	21	28	35	42	56	70	V
Maximum DC Blocking Voltage	V _{DC}	30	40	50	60	80	100	V
Maximum Average Forward Rectified Current (See Fig.1)	I _(AV)	10.0						A
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Super Imposed on Rated Load (JEDEC Method)	I _{FSM}	150						A
Peak Forward Voltage (Note1) IF=10A @T _J =25°C IF=10A @T _J =125°C IF=20A @T _J =25°C IF=20A @T _J =125°C	V _F	0.70 0.57 0.84 0.72		0.80 0.70 0.95 0.85		0.85 0.71 - -		V
Maximum DC Reverse Current at Rated DC Bolcking Voltage	I _R	0.1 15		0.1 10		0.1 6.0		mA
Typical Junction Capacitance (Note2)	C _J	400				1100		pF
Typical Thermal Resistance (Note3)	R _{θJC}	2.5				2.0		°C/W
Operating Temperature Range	T _J	-55 to +150						°C
Storage Temperature Range	T _{STG}	-55 to +175						°C

NOTES:1.300us pulse width,2% duty cycle.

2.Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.

3.Thermal resistance junction to case.



FIG. 1 - FORWARD CURRENT DERATING CURVE

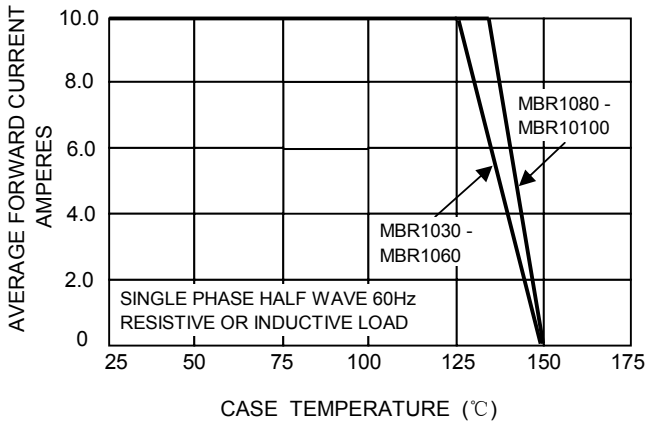


FIG. 2 - MAXIMUM NON-REPETITIVE SURGE CURRENT

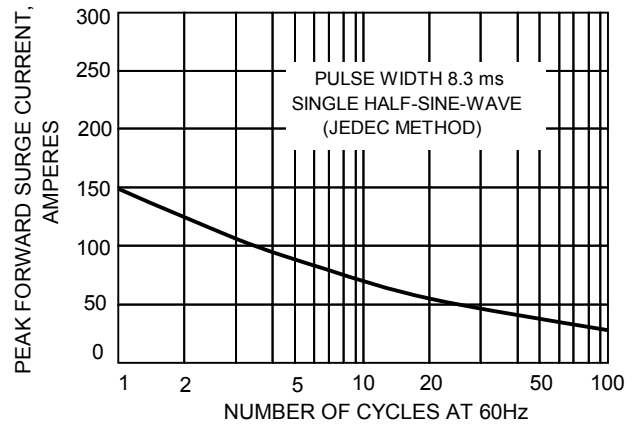


FIG.3-TYPICAL REVER CHARACTERISTICS

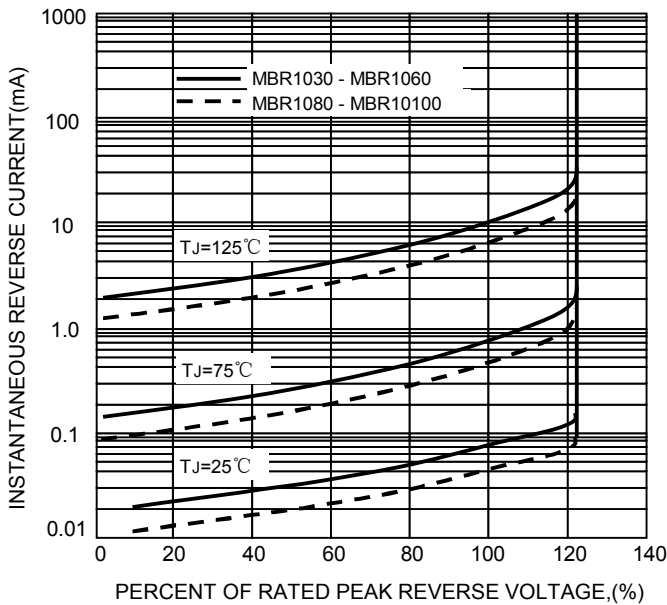


FIG.4-TYPICAL FORWARD CHARACTERISTICS

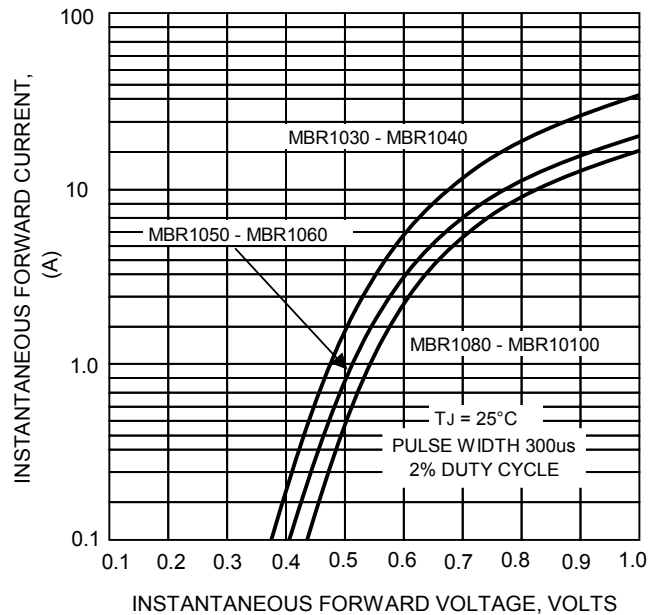


FIG.5 - TYPICAL JUNCTION CAPACITANCE

